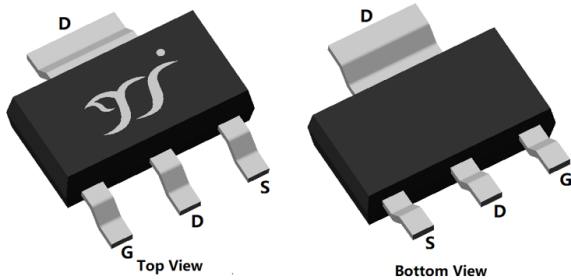
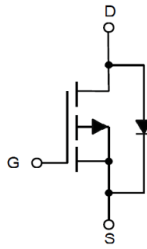


## P-Channel Enhancement Mode Field Effect Transistor



**SOT-223**



### Product Summary

- $V_{DS}$  -60 V
- $I_D$  -5 A
- $R_{DS(ON)}$ ( at  $V_{GS}=-10V$ ) <55 m $\Omega$
- $R_{DS(ON)}$ ( at  $V_{GS}=-4.5V$ ) <70 m $\Omega$

### General Description

- Split gate trench MOSFET technology
- Extremely low switching loss
- Excellent stability and uniformity
- Moisture Sensitivity Level 1
- Epoxy Meets UL 94 V-0 Flammability Rating
- Halogen Free

### Applications

- Power management
- Load switch

### ■ Absolute Maximum Ratings ( $T_A=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-source Voltage	$V_{DS}$	-60	V
Gate-source Voltage	$V_{GS}$	$\pm 20$	V
Drain Current	$I_D$	$T_A=25^\circ\text{C}$	-5
		$T_A=100^\circ\text{C}$	-3
Pulsed Drain Current <sup>A</sup>	$I_{DM}$	-25	A
Total Power Dissipation <sup>B</sup>	$P_D$	$T_A=25^\circ\text{C}$	1
		$T_A=100^\circ\text{C}$	0.4
Junction and Storage Temperature Range	$T_J, T_{STG}$	-55~+150	$^\circ\text{C}$

### ■ Thermal resistance

Parameter	Symbol	Typ	Max	Units
Thermal Resistance Junction-to-Ambient <sup>C</sup>	$R_{\theta JA}$	100	120	$^\circ\text{C/W}$

### ■ Ordering Information (Example)

PREFERRED P/N	PACKING CODE	Marking	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
YJM05GP06A	F2	05GP06	2500	5000	25000	13" reel



# YJM05GP06A

## ■ Electrical Characteristics (T<sub>J</sub>=25°C unless otherwise noted)

Parameter	Symbol	Conditions	Min	Typ	Max	Units
<b>Static Parameter</b>						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> = 0V, I <sub>D</sub> =-250μA	-60	-	-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =-60V, V <sub>GS</sub> =0V	-	-	-1	μA
		V <sub>DS</sub> =-60V, V <sub>GS</sub> =0V, T <sub>J</sub> =150°C	-	-	-100	
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> = ±20V, V <sub>DS</sub> =0V	-	-	±100	nA
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> = V <sub>GS</sub> , I <sub>D</sub> =-250μA	-1.5	-2	-3	V
Static Drain-Source On-Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =-10V, I <sub>D</sub> =-5A	-	40	55	mΩ
		V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-4A	-	50	70	
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =-5A, V <sub>GS</sub> =0V	-	-0.9	-1.2	V
Gate resistance	R <sub>G</sub>	f=1MHz, Open drain	-	12	-	Ω
Maximum Body-Diode Continuous Current	I <sub>S</sub>		-	-	-5	A
<b>Dynamic Parameters</b>						
Input Capacitance	C <sub>iss</sub>	V <sub>DS</sub> =-30V, V <sub>GS</sub> =0V, f=1MHz	-	1050	-	pF
Output Capacitance	C <sub>oss</sub>		-	380	-	
Reverse Transfer Capacitance	C <sub>rss</sub>		-	20	-	
<b>Switching Parameters</b>						
Total Gate Charge	Q <sub>g</sub>	V <sub>GS</sub> =-10V, V <sub>DS</sub> =-30V, I <sub>D</sub> =-5A	-	18.7	-	nC
Gate-Source Charge	Q <sub>gs</sub>		-	4.7	-	
Gate-Drain Charge	Q <sub>gd</sub>		-	3	-	
Reverse Recovery Charge	Q <sub>rr</sub>	I <sub>F</sub> =-5A, di/dt=100A/us	-	8	-	nC
Reverse Recovery Time	t <sub>rr</sub>		-	20	-	ns
Turn-on Delay Time	t <sub>D(on)</sub>	V <sub>GS</sub> =-10V, V <sub>DD</sub> =-30V, I <sub>D</sub> =-5A RGEN=2.2Ω	-	7.5	-	ns
Turn-on Rise Time	t <sub>r</sub>		-	40	-	
Turn-off Delay Time	t <sub>D(off)</sub>		-	43	-	
Turn-off fall Time	t <sub>f</sub>		-	55	-	

A. Repetitive rating; pulse width limited by max. junction temperature.

B. P<sub>d</sub> is based on max. junction temperature, using junction-case and junction-ambient thermal resistance.

C. The value of RθJA is measured with the device mounted on the minimum recommend pad size, in the still air environment with TA =25°C. The maximum allowed junction temperature of 150°C. The value in any given application depends on the user's specific board design.



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## Typical Electrical and Thermal Characteristics Diagrams

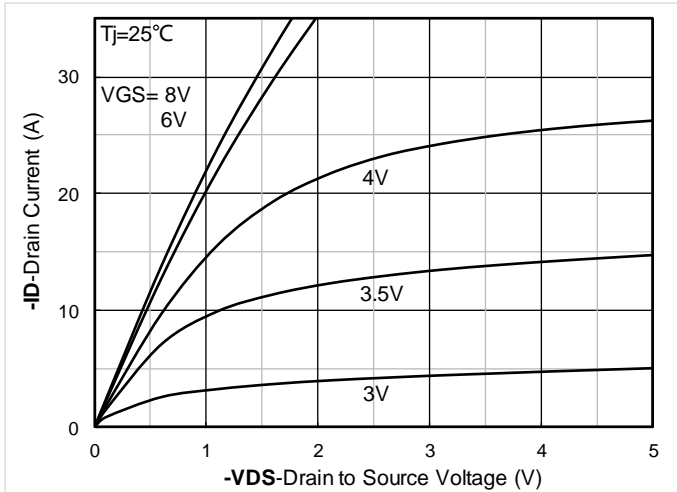


Figure 1. Output Characteristics

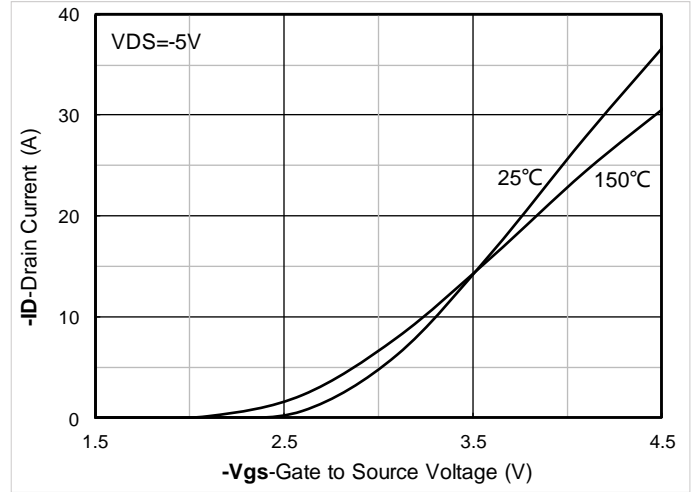


Figure 2. Transfer Characteristics

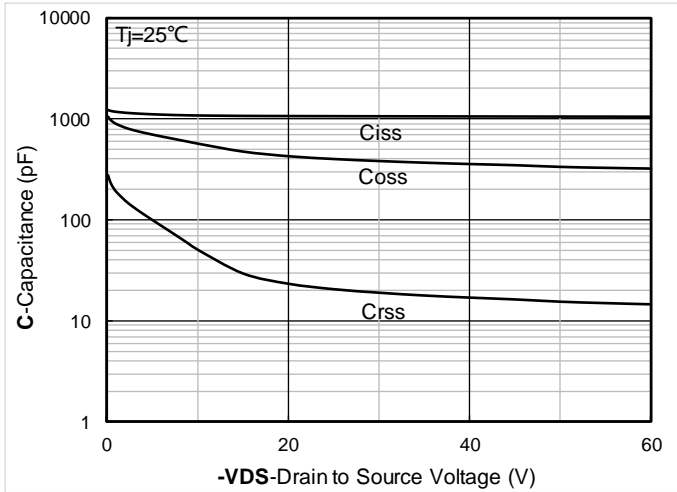


Figure 3. Capacitance Characteristics

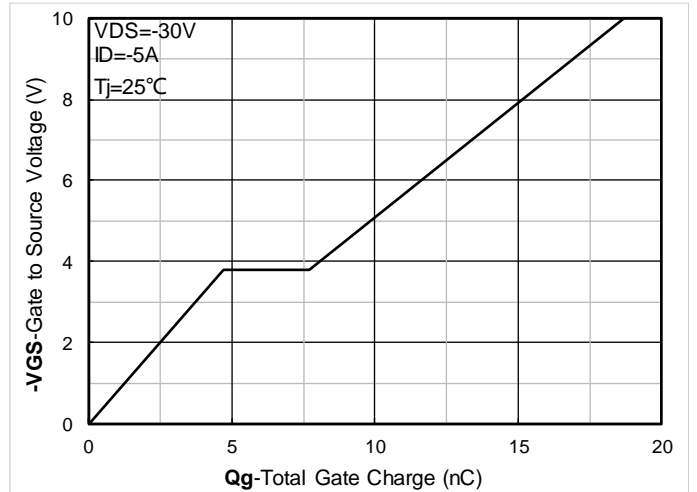


Figure 4. Gate Charge

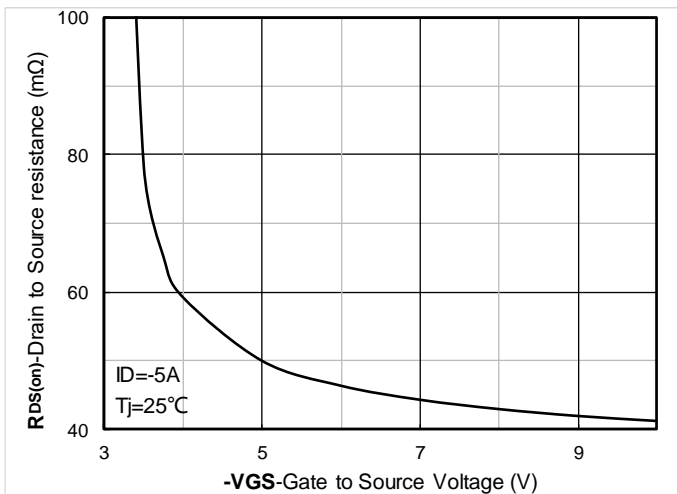


Figure 5. On-Resistance vs Gate to Source Voltage

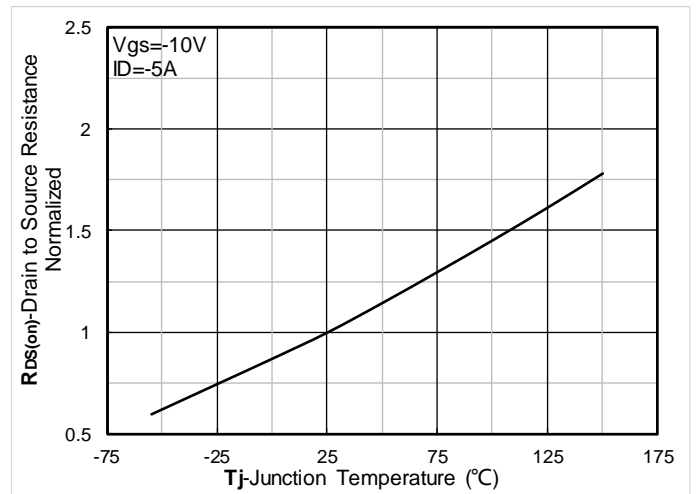


Figure 6. Normalized On-Resistance



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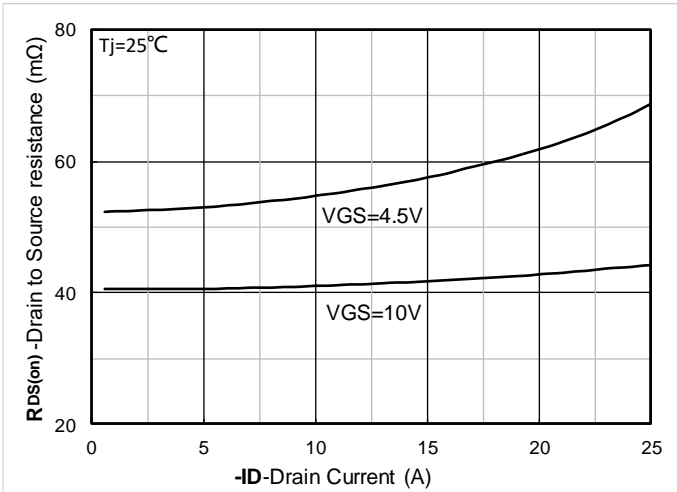


Figure 7.  $R_{DS(on)}$  VS Drain Current

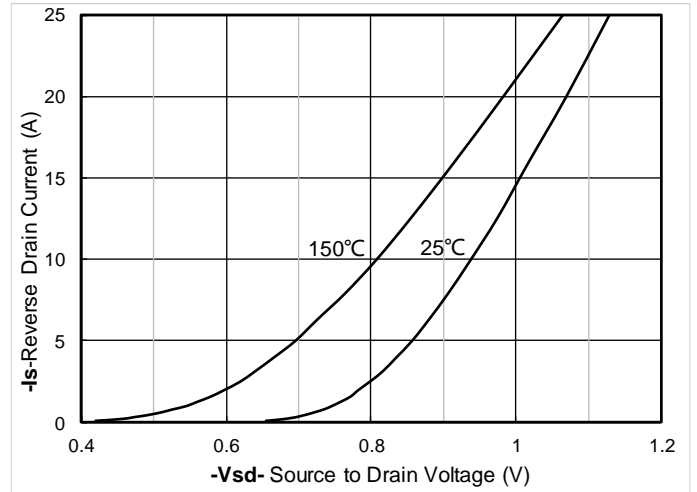


Figure 8. Forward characteristics of reverse diode

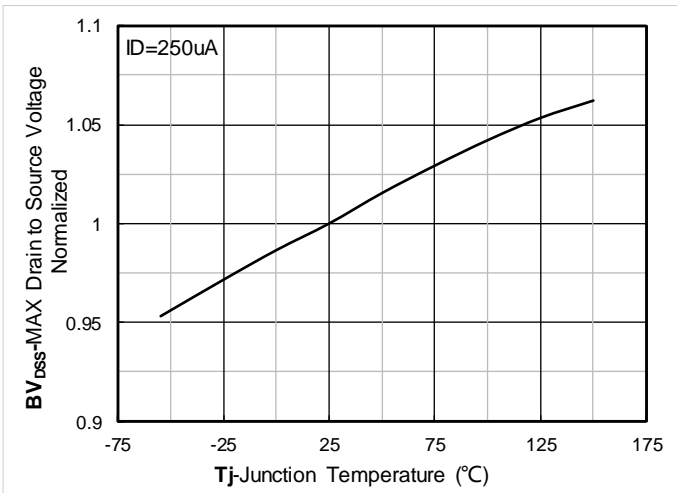


Figure 9. Normalized breakdown voltage

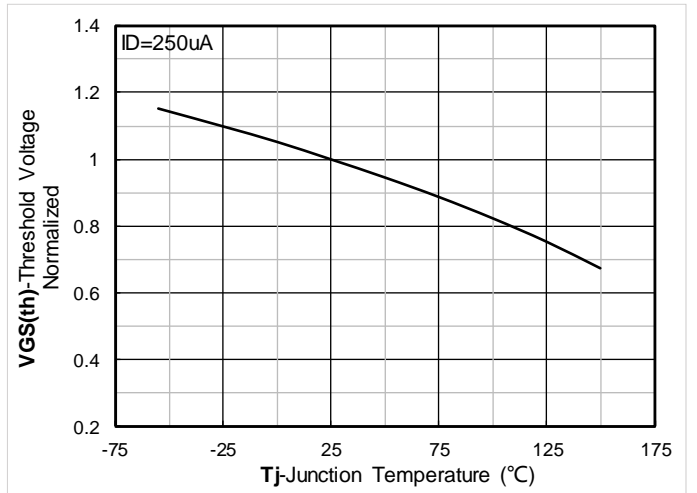


Figure 10. Normalized Threshold voltage

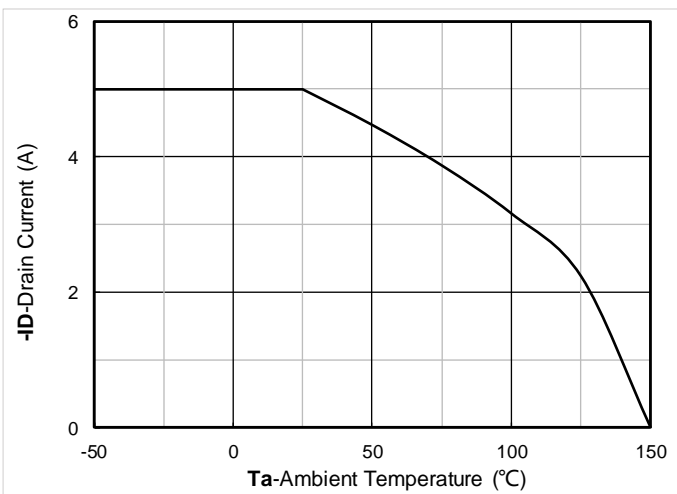


Figure 11. Current dissipation

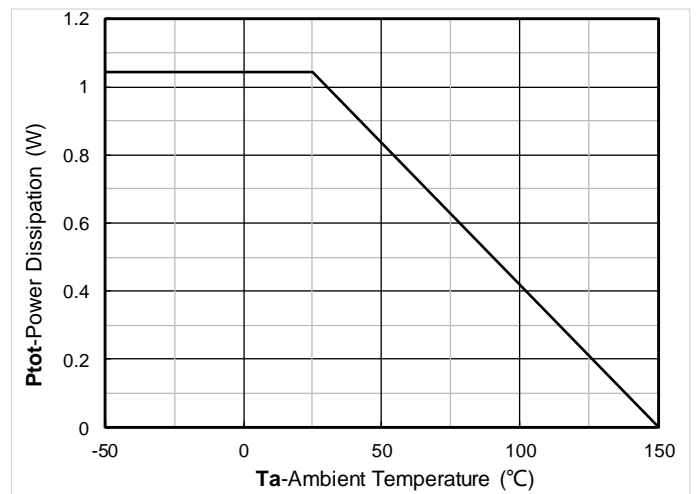


Figure 12. Power dissipation



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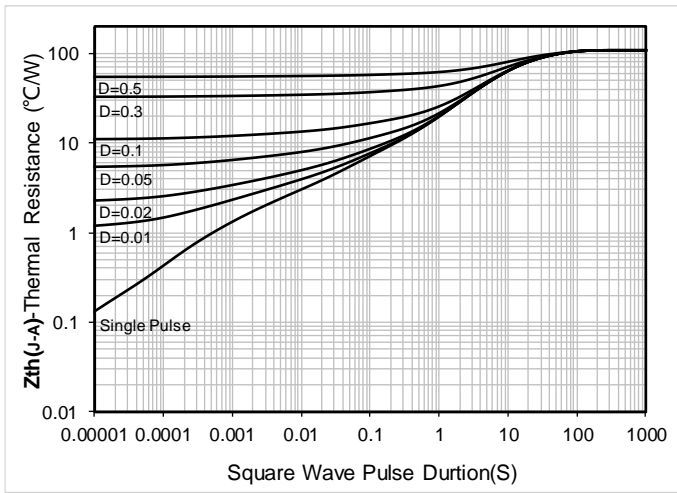


Figure 13. Maximum Transient Thermal Impedance

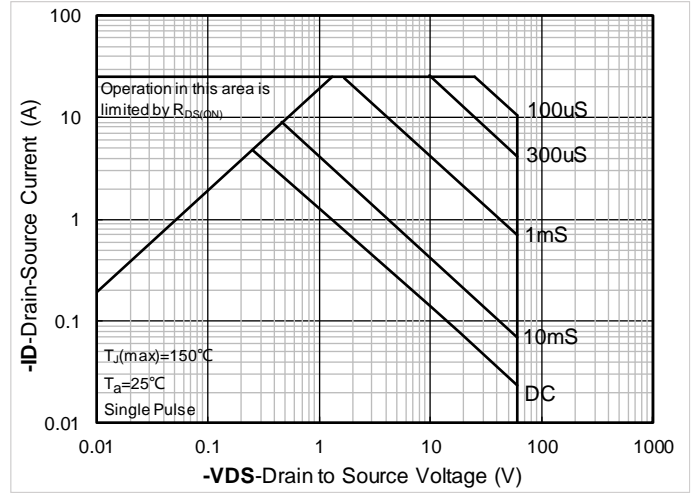
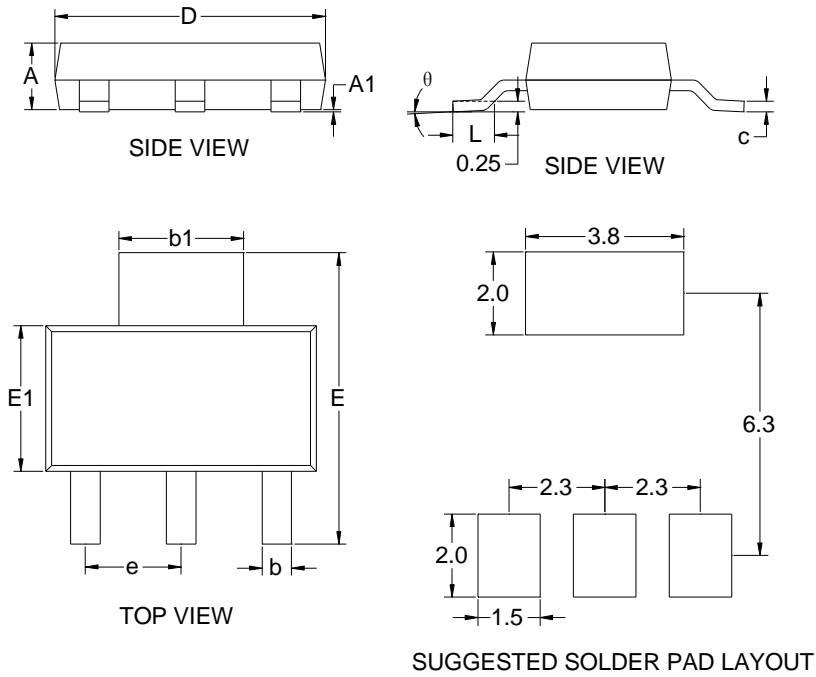


Figure 14. Safe Operation Area



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## ■ SOT-223 Package Information



DIMENSIONS				
DIM	INCHES		MM	
	MIN	MAX	MIN	MAX
A	0.0591	0.0670	1.5000	1.7000
A1	0.0008	0.0039	0.0200	0.1000
b	0.0259	0.0330	0.6600	0.8400
b1	0.1140	0.1220	2.9000	3.1000
c	0.0090	0.0138	0.2300	0.3500
D	0.2480	0.2640	6.3000	6.7000
E	0.2637	0.2874	6.7000	7.3000
E1	0.1290	0.1460	3.3000	3.7000
e	0.0866	0.0945	2.2000	2.4000
L	0.0295	0.0492	0.7500	1.2500
$\theta$	0°	10°	0°	10°



## YJM05GP06A

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